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3 TO 8 LINE DECODER DEMULTIPLEXER



#### **Description**

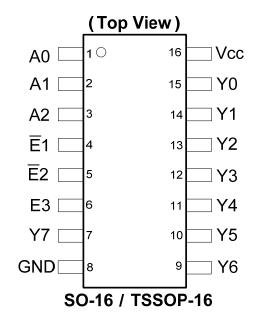
The 74HCT138 is a high speed CMOS device that is designed to be pin compatable with 74LS low power Schottky types.

The device accepts a three bit binary weighted address on input pins A0, A1 and A2 and when enabled will produce one active low output with the remaing seven being high.

There are two active LOW enable inputs  $\overline{E}1$  and  $\overline{E}2$ , and one active HIGH enable input E3. The disabled device state results in all outputs being high. The enable state occurs with  $\overline{E}1$  and  $\overline{E}2$  asserted low and E3 asserted high.

The multiple enable lines allow for the parallel expansion of decoders to create 4-to-16 line versions with no additional parts and 5-to-32 versions with the addition of a single inverter.

### **Pin Assignments**



#### **Features**

- Wide Supply Voltage Range from 4.5V to 5.5V
- Sinks or sources 8mA at  $V_{CC}$  = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 6.0V
- ESD Protection Tested per JESD 22
- Exceeds 200-V Machine Model (A115-A)
- Exceeds 2000-V Human Body Model (A114-A)
- Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Applications**

- Memory chip select decoding
- Demultiplexing
- Single line peripheral control
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



## **Pin Descriptions**

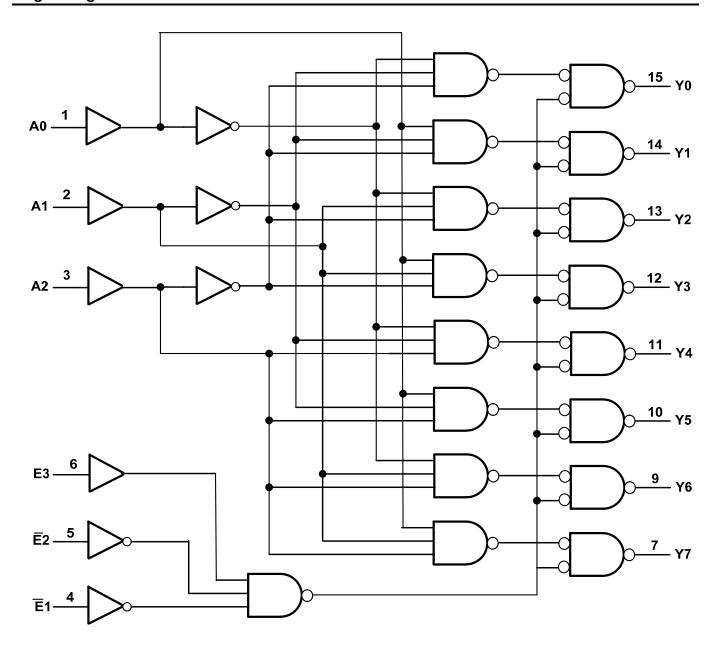
Pin Number	Pin Name	Description
1	A0	Address Input 0
2	A1	Address Input 1
3	A2	Address Input 2
4	E1	Enable Input 1 (active LOW)
5	E2	Enable Input 2 (active LOW)
6	E3	Enable Input 3 (active HIGH)
7	Y7	Output 7 (active LOW)
8	GND	Ground
9	Y6	Output 6 (active LOW)
10	Y5	Output 5 (active LOW)
11	Y4	Output 4 (active LOW)
12	Y3	Output 3 (active LOW)
13	Y2	Output 2 (active LOW)
14	Y1	Output 1 (active LOW)
15	Y0	Output o (active LOW)
16	V <sub>cc</sub>	Supply Voltage

# **Function Table Diagram**

	Control			Input		Output							
E <sub>1</sub>	E2	E3	A2	<b>A</b> 1	A0	<b>∀</b> 7	<u>₹</u> 6	<del>Y</del> 5	<b>∀</b> 4	<b>∀</b> 3	<b>∀</b> 2	<u>Y</u> 1	<del>Y</del> 0
Н	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Χ	Н	Х	_	-	-	_	-	-	_	-	-	-	_
Х	Х	L	_	-	-	-	-	-	-	-	-	-	-
L	L	Н	-	-	-	-	-	-	-	-	-	-	-
=	_	-	L	L	L	Н	Н	Н	Н	Н	Н	Н	L
-	_	_	L	L	Н	Н	Н	Н	Н	Н	Н	L	Н
-	_	_	L	Н	L	Н	Н	Н	Н	Н	L	Н	Н
-	_	_	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н
_	_	_	Н	L	L	Н	Н	Н	L	Н	Н	Н	Н
l	_	_	Н	L	Н	Н	Н	L	Н	Н	Н	Н	Н
	_	_	Н	Н	L	Н	L	Н	Н	Н	Н	Н	Н
=	=	=	Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н



## **Logic Diagram**





### Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to 7.0	V
VI	Input Voltage Range	-0.5 to 7.0	V
Vo	Voltage Applied to Output in High or Low State	-0.3 to V <sub>CC</sub>	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> > V <sub>CC</sub> + 0.5V	20	mA
Іок	Output Clamp Current V <sub>O</sub> < -0.5V	-20	mA
lok	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> + 0.5V	20	mA
I <sub>O</sub>	Continuous Output Current	+/- 25	mA
Icc	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C
Ртот	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	-	4.5	5.5	V
VI	Input Voltage	-	0	Vcc	V
Vo	Output Voltage	Active Mode	0	V <sub>CC</sub>	V
Δt/ΔV	Input transition rise or fall rate	V <sub>CC</sub> = 4.5V	-	100	ns/V
T <sub>A</sub>	Operating free-air temperature	-	-40	125	°C

Note: 5. Unused inputs should be held at  $V_{CC}$  or Ground.



## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	<u>.</u>	<b>-</b>		.,	Т	<sub>A</sub> = 25°	С	-40°C t	o 85°C	-40°C to	o 125°C	
Symbol	Parameter	Test Con	ditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-level Input Voltage	-		4.5V to 5.5V	2.0	1.6	ı	2.0	ı	2.0	ı	٧
V <sub>IL</sub>	Low-level input voltage	_		4.5V to 5.5V	Ü	1.2	0.8	-	0.8	_	0.8	V
	High Level	Ι <sub>ΟΗ</sub> = -20 μ/	4	4.5V	4.4	4.5	ı	4.4	ı	4.4	ı	
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -4 mA	1	4.5V	3.98	4.32	ı	3.85	1	3.7	I	V
	Low-level	I <sub>OL</sub> = 20 μA		4.5V		0	0.1	ı	0.1	I	0.1	
V <sub>OL</sub>	Output Voltage	I <sub>OL</sub> = 4 mA		4.5V	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>1</sub>	Input Current	V <sub>I</sub> =GND to 5.5 V		5.5V		-	±0.1	-	± 1	_	± 1	μA
Icc	Supply Current	$V_1 = GND$ $I_0=0$	or V <sub>CC</sub>	5.5V		-	8.0	-	80	_	160	μA
		Test Per Pin	PINS An		I	150	540	ı	675	ı	735	μA
	Additional	V <sub>1</sub> =	PIN En		-	125	450	I	563	ı	613	
$\Delta I_{CC}$	Supply Current	Vcc -2.1 V Other $V_1 = Vcc$ or GND $I_0=0$	PIN E3	4.5V to 5.5V	-	100	360	-	450	-	490	μА
Ci	Input Capacitance	$V_i = V_{CC}$ or	GND	5.5V	-	4	10	-	10	-	10	pF

# **Switching Characteristics**

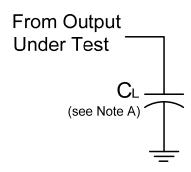
Symbol /	Pins	Test	Vcc		T <sub>A</sub> =25°C		-40°C to 85°C		-40°C to 125°C		Unit
Parameter	PINS	Conditions	VCC	Min	Тур.	Max	Min	Max	Min	Max	Unit
	A = 4 = <del>V</del> =	F: 0	4.5V	_	20	35	_	35	-	45	
$t_{PLH,}$	An to $\overline{Y}$ n	Figure 2	5.0V	-	17	-	_	_	-	-	
$t_PLH$	E3 to $\overline{Y}$ n	Figure 2	4.5V	-	18	40	=	40	=	45	
Propagation			5.0V	-	19	=	=	=	=	=	ns
Delay	Ēn to ₹n	to $\overline{Y}$ n Figure 2	4.5V	-	19	40	=	40	=	45	
			5.0V	=	19	=	=	-	=	=	
t <sub>TLH,</sub> t <sub>THL</sub> Transition Time	₹n	Figure 2	4.5 V	_	7	15	-	15	-	110	ns



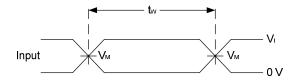
### Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter		Parameter	Test Conditions	V <sub>cc</sub> = 5V TYP	Unit
	$C_{pd}$	Power Dissipation Capacitance	f = 1 MHz all outputs switching-no load	21	pF

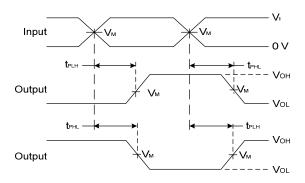
### **Parameter Measurement Information**



V <sub>cc</sub>	Inp	outs	V <sub>M</sub>	C <sub>L</sub>	
	$V_i$ $t_r/t_f$				
4.5V	3 V	6ns	V <sub>CC</sub> /2	50pF	
5.0V	3 V	6ns	V <sub>cc</sub> /2	15pF used for 5V typical test	



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

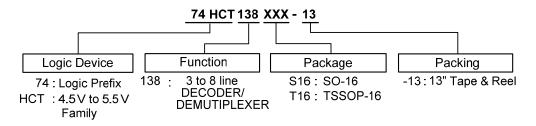
Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. Inputs are measured separately one transition per measurement
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$

Figure 1. Load Circuit and Voltage Waveforms



## **Ordering Information**

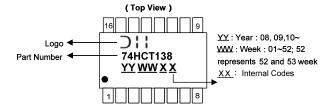


Davies	Doolsono Codo	Packaging	7" Tape and Reel(Note 7)		
Device	Package Code (Note 6)		Quantity	Part Number Suffix	
74HCT138S16-13	S16	SO-16	2500/Tape & Reel	-13	
74HCT138T16-13	T16	TSSOP-16	2500/Tape & Reel	-13	

Notes:

## **Marking Information**

#### (1) SO-16, TSSOP-16



Part Number	Package
74HCT138S16	SO-16
74HCT138T16	TSSOP-16

Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <a href="http://www.diodes.com/datasheets/ap02001.pdf">http://www.diodes.com/datasheets/ap02001.pdf</a>. <a href="http://www.diodes.com/datasheets/ap02001.pdf">http://www.diodes.com/datasheets/ap02001.pdf</a>.

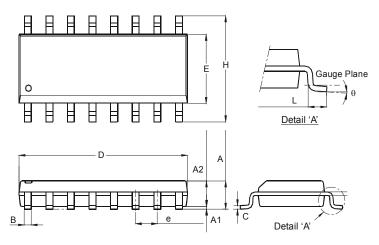
<sup>7.</sup> The taping orientation is located on our website at <a href="http://www.diodes.com/datasheets/ap02007.pdf">http://www.diodes.com/datasheets/ap02007.pdf</a>



## Package Outline Dimensions (All dimensions in mm.)

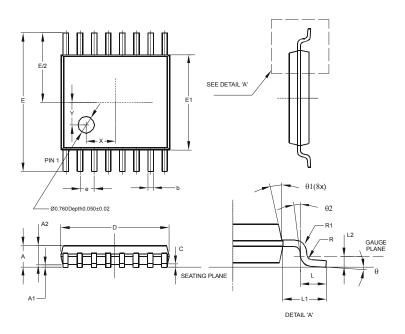
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-16



	SO-16						
Dim	Min	Max					
Α	1.40	1.75					
A1	0.10	0.25					
A2	1.30	1.50					
В	0.33	0.51					
С	0.19	0.25					
D	9.80	10.00					
Е	3.80	4.00					
е	1.27	Тур					
Н	5.80	6.20					
L	0.38	1.27					
Θ	0°	8°					
All D	imension	s in mm					

### Package Type: TSSOP-16



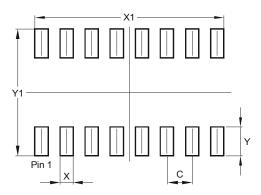
TSSOP-16						
Dim	Min	Max	Тур			
Α	-	1.08	-			
<b>A</b> 1	0.05	0.15	-			
A2	0.80	0.93	-			
b	0.19	0.30	ı			
С	0.09	0.20	-			
D	4.90	5.10	-			
Е	6	.40 BS	SC .			
E1	4.30	4.50	1			
е	0	.65 BS	SC			
L	0.45	0.75	-			
L1	1	.00 R	EF			
L2	0	.25 BS	SC SC			
R	0.09	-	-			
R1	0.09	ı	-			
X	ı	ı	1.350			
Υ	ı	ı	1.050			
Θ	0°	8°	-			
Θ1	5°	15°	-			
Θ2	0°	-	-			
All Dimensions in mm						



## **Suggested Pad Layout**

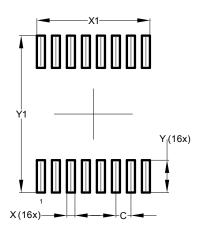
 $Please see AP02001 \ at \ http://www.diodes.com/datasheets/ap02001.pdf \ for \ the \ latest \ version.$ 

#### Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Υ	1.450
Y1	6.400

### Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Υ	1.400
Y1	6 800



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